L Number	Hits	Search Text	DB	Time stamp
1	1	("6277699").PN.	USPAT	2004/06/07 17:20
2	3	(("6091120") or ("5089863") or	USPAT	2004/06/07 17:21
		("5384479")).PN.]	2001,00,0, 1,.21
3	0	((("6091120") or ("5089863") or	USPAT	2004/06/07 17:21
		("5384479")).PN.) and (tungsten and		
İ		(hydrogen adj bromide))		
-	3139	438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/07 17:19
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.		
-	1871	438/585.ccls. or 438/592.ccls. or	USPAT	2004/06/04 14:43
		438/595.ccls.		
-	4321	(438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 14:43
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.) or		
		(438/585.ccls. or 438/592.ccls. or		
	0.5	438/595.ccls.)		
-	85	((438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 14:45
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.) or		•
1		(438/585.ccls. or 438/592.ccls. or		
		438/595.ccls.)) and (MOSFET and		
		anisotropic\$4 and isotropic\$4 and etch\$3		
_	124	and tungsten and polysilicon) ((438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 14:51
]	124	438/301.ccls. or 438/303.ccls. or	USPAT	2004/06/04 14:51
<u> </u>		438/305.ccls. or 438/306.ccls.) or		
		(438/585.ccls. or 438/592.ccls. or		
		438/595.ccls.)) and (MOSFET with (channel		
		adj length))		
-	10	MOSFET with (t-gate)	USPAT	2004/06/04 17:56
	1558	438/301.ccls. or 438/303.ccls.	USPAT	2004/06/04 15:42
_	1499	438/305.ccls. or 438/306.ccls.	USPAT	2004/06/04 15:42
-	814	438/197.ccls. or 438/299.ccls.	USPAT	2004/06/04 17:56
l – i	3139	438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 17:56
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.		
-	1236	(438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 17:56
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.) and MOSFET		
-	814	438/197.ccls. or 438/299.ccls.	USPAT	2004/06/04 17:56
-	934	((438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 18:01
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.) and		
		MOSFET) not (438/197.ccls. or	i	
	000	438/299.ccls.)		0004/05/04 55 55
-	830	(((438/197.ccls. or 438/299.ccls. or	USPAT	2004/06/04 18:01
		438/301.ccls. or 438/303.ccls. or		
		438/305.ccls. or 438/306.ccls.) and		[
		MOSFET) not (438/197.ccls. or 438/299.ccls.)) and channel		
_	10311	MOSFET with channel	USPAT	2004/06/04 18:08
_	1106	(MOSFET with channel) and (gate and	USPAT	2004/06/04 18:08
	1100	tungsten and polysilicon)	JOINI	2007/00/04 10:02
_	10	((MOSFET with channel) and (gate and	USPAT	2004/06/04 18:02
	**	tungsten and polysilicon)) and (hydrogen	331711	2003/00/03 10:02
		adi bromide)		
-	122	(MOSFET with channel) and ((hydrogen adj	USPAT	2004/06/04 18:08
		bromide) or HBr)		
-	112	((MOSFET with channel) and ((hydrogen adj	USPAT	2004/06/04 18:08
		bromide) or HBr)) not (((MOSFET with		
		channel) and (gate and tungsten and		
		polysilicon)) and (hydrogen adj bromide))		
-	103	(((MOSFET with channel) and ((hydrogen adj	USPAT	2004/06/04 18:09
		bromide) or HBr)) not (((MOSFET with		
		channel) and (gate and tungsten and		
		<pre>polysilicon)) and (hydrogen adj bromide)))</pre>		
		and (((hydrogen adj bromide) or HBr) with		
		etch\$3)]	